

SPICE Device Model Si9435BDY

Vishay Siliconix

P-Channel 30-V (D-S) MOSFET

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

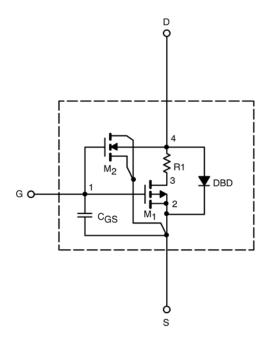
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125° C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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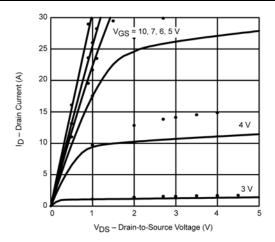
SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	2.1		V
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	133		Α
Drain-Source On-State Resistance ^a	r _{DS(on)}	$V_{GS} = -10 \text{ V}, I_D = -5.7 \text{ A}$	0.032	0.033	Ω
		$V_{GS} = -6 \text{ V}, I_D = -5 \text{ A}$	0.041	0.043	
		$V_{GS} = -4.5 \text{ V}, I_D = -4.4 \text{ A}$	0.055	0.056	
Forward Transconductance ^a	g _{fs}	$V_{DS} = -15 \text{ V}, I_D = -5.7 \text{ A}$	11	13	S
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S}$ = -2.3 A, $V_{\rm GS}$ = 0 V	-0.82	-0.80	V
Dynamic ^b			-		
Total Gate Charge	Q _g	V_{DS} = -15 V, V_{GS} = -10 V, I_{D} = -3.5 A	13	16	nC
Gate-Source Charge	Q_{gs}		2.3	2.3	
Gate-Drain Charge	Q_{gd}		4.5	4.5	
Turn-On Delay Time	t _{d(on)}	$V_{DD} = -15 \text{ V}, R_L = 15 \Omega$ $I_D \cong -1 \text{ A}, V_{GEN} = -10 \text{ V}, R_G = 6 \Omega$	31	30	ns
Rise Time	t _r		19	14	
Turn-Off Delay Time	$t_{d(off)}$		72	42	
Fall Time	t _f		16	30	

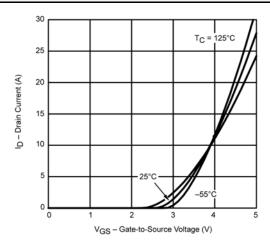
Notes a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2\%.$ b. Guaranteed by design, not subject to production testing.

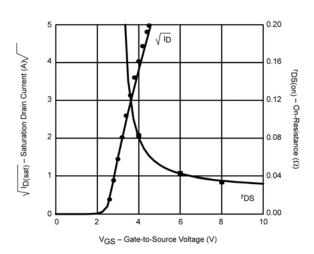


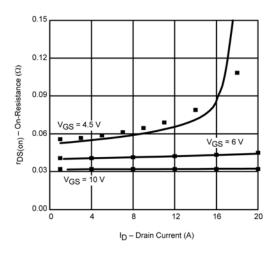
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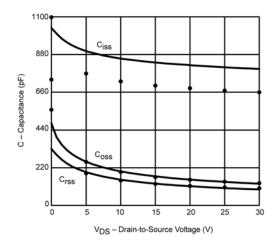
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

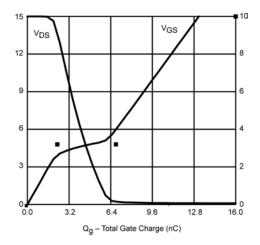












Note: Dots and squares represent measured data.



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